NSN 5961-01-071-7362

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-071-7362 **Inclosure Material:** Metal **Overall Length:** Between 0.412 inches and 0.450 inches **Overall Diameter:** Between 0.667 inches and 0.685 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.685 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 60.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig:

A110a0